Tetra Point W etting at the Free Surface of Liquid G a-Bi

P. Huber¹, O. G. Shpyrko¹, P.S. Pershan¹, B.M. Ocko², E. D.M. as², and M. Deutsch³

¹Departm ent of Physics, Harvard University, Cambridge MA 02138

²D epartm ent of Physics, Brookhaven National Lab, Upton NY 11973

³D epartm ent of Physics, Bar-Ilan University, Ram at-Gan 52900, Israel

(Dated: April 14, 2024)

A continuous surface wetting transition, pinned to a solid/liquid/liquid/vapor tetra coexistence point, is studied by x-ray re ectivity in liquid Ga-B ibinary alloys. The short-range surface potential is determ ined from the measured temperature evolution of the wetting lm. The therm all uctuations are shown to be insu cient to induce a noticeable breakdown of mean-eld behavior, expected in short-range-interacting system s due to their $d_u = 3$ upper critical dimensionality.

PACS num bers: 61.25 M v, 61.30 H n, 68.10.{m, 61.10.{i

The wetting transition, predicted independently by Cahn[1] and by Ebner and Saam [2] in 1977, has attracted much theoretical[3] and experimental[4] attention, due to its importance for fundamental physics [3]and for applications [5]. A lm ost all experim ental and theoretical studies of the wetting transition published to date address liquids interacting through long-range van der W aals potentials, for which the upper critical dim ensionality is $d_1 < 3$. Thus, for a d = 2 surface on a d = 3 bulk mean-eld (MF) behavior is expected. By contrast, wetting phenom ena in liquids interacting by a short range potential (SRW), where $d_u = 3$, allow, in principle, to explore the regime where the MF behavior breaks down due to uctuations and the renorm alizationgroup (RG) approach becom es applicable. How ever, due to extrem ely dem anding experim ental requirem ents and the lack of a theory allowing to predict the SRW interaction param eters only a single experim ental study addressing uctuation e ects on SRW was published to date [6]. Even that study employs van-der-W aals-interacting liguids, and SRW was achieved by tuning the wetting tem perature, T_W , very close to the critical point, T_C . The authors' estimates of the uctuations' magnitude predicted a RG behavior. Nevertheless, a MF behavior was found and interpreted as an "apparent failure" of RG theory to account for SRW .

W e present here an x-ray study of wetting in a G a-Bi binary alloy, which interacts by a short range screened C oulom b potential at all concentrations. This allows achieving SRW far from T_c , thus m inimizing any possible in uence of the criticality on the wetting transition. M oreover, the x-ray techniques employed allowed the determ ination of the wetting layer's internal structure on an Angstrom scale and dem onstrated the strong com positional gradient within the wetting lm, predicted by density functional calculations[2, 7]. The wetting transition in this system is pinned to a bulk monotectic tem – perature, T_M , creating a rare case of tetra point wetting, where four phase coexist in the bulk: a G a-rich liquid, a Bi-rich liquid, a solid Bi and a vapor[8, 9]. We determ

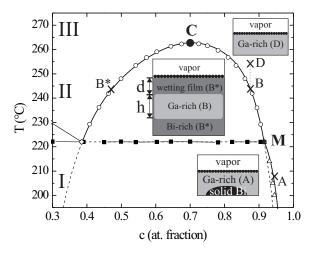


FIG.1: The atom ic fraction (c)-Tem perature (T) bulk phase diagram of G a-B i. The symbols indicate coexistence lines of P redel's phase diagram [10]. The lines show the phase boundaries calculated from therm odynam ic data [23]. The dashed lines represent the m etastable extension of the l/lcoexistence line below T_M . The points are: C-bulk critical point, M-m onotectic point, A,B,D-points on the experimental path. The insets illustrate the surface and bulk phases. In region II the wetting Im is 50 A thick and the Ga-rich uid is 5 mm thick. The bold surface lines in the insets symbolize the Birm onolayer.

com position, thickness and internal structure along a trajectory in the phase diagram which includes several phase boundaries and the tetra point. The study highlights the intim ate relation between the wetting layer's structure and the bulk phase diagram. The T-dependence of the wetting lm's structure yields the rst quantitative determ ination of a M F short-range surface potential governing the wetting transition. Finally, from a RG analysis we estim ate the in uence of therm all uctuations on the observed tetra point wetting.

The measured [10] bulk phase diagram of Ga-Bi is shown in Fig.1, with cartoons relating the surface phases

to the bulk ones. For all T a G ibbs-adsorbed B im onolayer is found at the free surface[11, 12]. In Region I, T < $T_{\rm M}$, the B im onolayer and the solid B i coexist with a G a-rich liquid. In Region II, $T_{\rm M}~<~T~<~T_{\rm C}$, the bulk separates m acroscopically into immiscible G a-rich and B i-rich liquids, and the denser B i-rich phase sinks to the bottom of the sample pan. However, the B i-rich phase also wets the free surface by intruding between the G a-rich low density phase and the B im onolayer, in deance of gravity. In the hom ogeneous part of the phase diagram, region III, only the B im onolayer is found at the free surface [13]. The four phases, solid B i, B i-rich liquid, G a-rich liquid, and vapor coexist at the boundary between regions I and II, $T_{\rm M}$, rendering it a solid-liquidliquid-vapor tetra point.

X-ray re ectivity measurements were carried out at beam line X 22B, N SLS, at a wavelength = 1:54 A. The intensity R (qz) re ected from the surface, is measured as a function of the norm alcom ponent q_z of the momentum transfer and allows determ ining the surface-norm al electron density pro le (z) [14]. The Ga-Bialloy was prepared in an inert-gas box using > 99:9999% pure m etals. A solid Bipellet was covered by an amount of liquid Ga required for a nom inal concentration $c_{nom} = 88$ at% Ga. It was then transferred in air into an ultrahigh vacuum chamber. A day of bake-out yielded a pressure of 10¹⁰ torr. The residual surface oxide on the liquid's surface was removed by sputtering with Ar⁺ ions. Using therm occuple sensors and an active tem perature control on the sample pan and its adjacent therm alshield a tem perature stability and uniform ity of 0:05 C was achieved $\operatorname{near} T_{M}$.

X-ray re ectivity R (qz) was measured at selected tem peratures on the path A! M. The standard procedure [15] for determining (z) from the measured R (q_z) is to construct a physically motivated model for (z) and t its Fourier transform to the measured $R(q_z)=R_F(q_z)$. R_F (q_z) is the Fresnel re ectivity from an ideally at and sharp surface having the electron density of the Ga-rich liquid. W e em ploy a two-box m odel[11], w here the upper box represents the G ibbs adsorbed Bim onolayer, and the lower box - the Birrich wetting lm. The model also includes three roughnesses for the three interfaces: vapor/Bim onolayer, Bim onolayer/Birich lm, and Birich lm/Ga-rich subphase. The ts (lines) to the measured (points) $R = R_F$ are shown in Fig. 2(a), and the corresponding (z) pro les - in Fig. 2(b). At point A $(T_A = 205 \text{ C}, \text{ in set to F ig } 2 \text{ (a)}), \text{ typical of region I, R = R_F}$ exhibits a pronounced maximum at $q_z = 0.8A^{-1}$, indicative of a high electron density layer at the surface. The (z) obtained from the t is consistent with a seqregated m onolayer of pure Biat the free surface[11, 12]. As the tem perature is increased towards M, a peak in 02A¹, gradually shift- $R = R_F$ starts to develop at q_z ing to lower q. This behavior manifests the formation of the wetting layer and its continuous growth in thick-

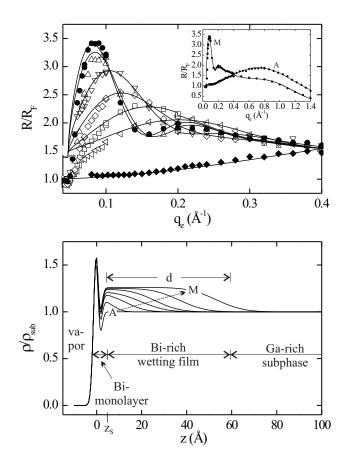


FIG.2: (a) $R = R_F$ for selected temperatures $T_A \quad T \quad T_M$: () 205:0 C = T_A , (/) 218:9 C, () 220:4 C, () 221:0 C, (5) 221:5 C, (4) 221:8 C, () 222:0 C = T_M . Solid lines: ts to a two-box model of (z). (b) Fit-re ned electron density pro les (z) for aforementioned T's with $T_A \quad T \quad T_M$, sub = electron density of Ga-rich subphase. A and M mark (T_A) and (T_M), respectively.

ness upon approaching $T_{\rm M}$. For the fully-form ed wetting layer at M ($T_{\rm M}$ = 222:0 C), R=R_F shows two low-q_z peaks, characteristic of a thick lm, and the typelds a maximal lm density of = $_{\rm subphase}$ = 1:26 as shown in Fig. 2 (b). This agrees well with the value of 1:25 calculated for this ratio from the phase diagram at $T_{\rm M}$. The t-re ned 50A lm thickness also agrees with ellipsom etric measurements[16]. As can be seen in Fig. 2 (b), the evolution of the density pro les along the path A! M proceeds via highly inhom ogeneous wetting lm s that are similar to the microscopic density pro les calculated using density functional theory [2, 7].

The surface and bulk transitions at $T_{\rm M}$ are driven by the excess free energy, $_{\rm m}$, of the m etastable Birrich phase over that of the Garrich phase. Thus, to relate the observed continuous surface transition to the rst-order bulk transition at $T_{\rm M}$, we replot in Fig. 3(a) the (c;T) phase diagram of Fig. 1 on the ($_{\rm m}$;T) phase.

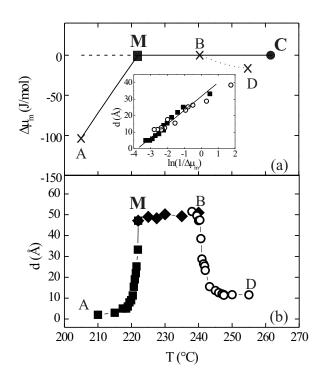


FIG.3: (a) ($_{\rm m}$,T) phase diagram : (A-M) is the liquidsolid, and (M-C) is the liquid/liquid coexistence lines. The path B-D is in the single phase region, and M and C are the monotectic and critical points. Inset: e ective wetting layer thickness d on A! M (squares) and B! D (open circles). The solid line is a t to the A! M d values. (b) The measured d along the experimental path.

For $T > T_M$, the $1/1\,coexistence$ line transforms into a straight line at ($_m$ = 0,T) extending from M to C. For $T < T_M$ the metastable $1/1\,coexistence$ line (dashed line) extends horizontally below T_M , while the solid-Bi/Ga-rich coexistence line goes below the metastable line from M to A. This illustrates D ietrich and Schick's observation [8] that the path leading to coexistence on heating from A to M is dictated by the topology of the phase diagram and corresponds to a path which probes "com plete wetting": $_m$! 0 on the path A ! M.

To determine the surface potential, we_Rde ne an ____ [(z) e ective wetting Im thickness, d = Garich ⊨[Birich $_{\text{Garich}}$]dz. Here z_{s} is the top of the wetting lm as marked in Fig. 2(b), and $_{Birich}$, Garich are the electron densities of the coexisting bulk liquid phases, calculated from the phase diagram . The d values calculated from the re ectivity ts along A! M, M! B, and B! D are plotted in Fig. 3(b). A long A! M a continuous increase in d is observed, while on the oncoexistence M ! B path a constant d 50 A is found. This is in agreem ent with the predictions for SRW : a continuous d grow th lim ited by gravity e ects[4]. At B the G a concentration reaches its nom inal value, $c_{nom} = 88$

at%, in the hom ogeneous liquid phase (region III).Upon further increase of T c remains unchanged. The sample leaves the $1/1 \operatorname{coexistence} \operatorname{line}$, m oving further into region III, and the wetting lm vanishes continuously. Further details of the M ! D path are discussed elsewhere [13].

As implied by the sim ilarity to Ebner and Saam 's[2] results, a detailed calculation of the wetting Im 's inhom ogeneity will require either a density functional analysis, or some other equivalent approach. Nevertheless, even a sim ple m odel approxim ating the wetting layer by a slab of thickness d allows a condent determination of the surface potential. For thism odel, the grand canonical potential s at the surface is given in the MF approxim ation by $_{S} = N A_{0} [d + _{M F} e^{d - _{M F}}]$ with a shortrange potential of decay length $_{\rm M\ F}$ and amplitude $% 10^{-1}$. Here = m + _q is the excess G ibbs Free E nergy of the Birich wetting phase over that of the Garich phase, $_{g} = g h V_{m}$ is the gravitational energy paid and for having the heavier Bi-rich phase at the surface. The particle number density per unit volume is N, A_0 is an arbitrary surface area, is the mass density di erence of the two phases, V_m is the molar volume of the Birich phase, and h is the height di erence between top and bottom. The equilibrium thickness, d, is that minim izing $s:\frac{d}{dd} = 0$ [3]. Neglecting the gravitational term for points o 1/1 coexistence yields: d = M_F ln (= m). The inset in Fig. 3 (a) shows the experim entald values on the path A! M (solid squares). The clear linear dependence on $\ln(1=)$ con rms the major theoretical predictions for SRW : a continuous growth and a logarithm ic divergence of the wetting lm 's thickness[3]. A t of d (line) to the experimental d (solid points) yields $_{MF}$ = 6:3 A and = 43 J/m ol. Both values are reasonable for such a metallic system . The value of corresponds to a change in surface energy upon wetting of about 400 m Jm² which is consistent with surface energy m easurem ents on G a-Bialloys[17], and G a-Pb ones [9]. It is interesting to compare the behavior of d for the path A! M with that along the path B! D, shown in the inset of Fig. 3 (open circles). The values overlap for m ost of the path, dem onstrating that the behavior along A! M is the same as can be observed for any other path probing complete wetting, e.g. the path B! D which is solely determ ined by the choice of c_{nom} .

The analysis above exhibits a very good agreement of the experimental SRW results with the universal behavior predicted by MF theory. However, it is important to note that this does not automatically mean a failure of the RG predictions for a non-universal SRW behavior in our, and other, $d_u = 3$ systems. Both MF and RG approaches yield here a continuous, logarithm ic divergence of d at T_W , but with di erent amplitudes for d [3, 18]. For MF, the amplitude is $_{MF}$ while for RG, where d $_{RG}$ (1 + !=2) ln (1=), the amplitude is $_{RG}$ (1 + !=2). The "capillary parameter" != $k_B T_W = (4 - \frac{2}{b})$ (where b is the bulk correlation length, and is the 1/1 in-

terfacial tension) measures the magnitude of the dom inant thermal uctuations in the system, the thermally induced capillary waves at the 1/1 interface of the coexisting Bi-and Ga-rich liquids. Hence, ! measures the deviation from a M F behavior, which, of course, neglects all uctuations. A calculated [22] = $4m Jm^2$ and a b = 6:1 1 A estimated from the two-scale factor universality (TSFU) theory for bulk dem ixing in Ga-Bi[19], yield $!(T_M) = 0.3$ 0.2. This is well within the ! < 2range, where RG analysis predicts only a mild e ect on complete wetting [18]. Indeed, $_{RG} = 5:4 \text{ A is only}$ 15 % smaller than MF = 63 A above. The two values are close, and in reasonable agreem ent with the value of $_{\rm b}$ expected from the TSFU $[\beta]$. Thus, a clear distinction between RG and MF behavior can not be drawn in our case.

F inally, we compare the measured gravity-lim ited maxim althickness of 50 A along M ! B with theory. O n coex- $_{\rm m}$ = 0 and thus $d_{\rm q}$ = $_{\rm R\,G}$ In (= istence q). Using = 43 J/m oland the known m aterial constants in yields $d_{grav} = 15:6_{RG}$ 85 A. Since this analysis does not take into account the excess energy associated with concentration gradients across the interfaces som e overestimation of d_{α} is not too surprising. However, even this rough calculation shows that the wetting Im thickness is expected to be on a mesoscopic rather than on the m acroscopic length scale observed for sim ilar wetting geom etries in systems governed by long-range, dispersion forces[4].

W e presented here the rst detailed, Angstrom resolution study of a short-range wetting transition at the free surface of the binary Ga-Biliquid alloy. The characteristic properties of SRW, a logarithm ic divergence of the wetting layer's thickness upon approaching the transition, are clearly exhibited by the measurements. The observed strongly inhom ogeneous internal structure of the wetting layer is similar to that obtained from density functional calculations of wetting at a hard wall[2, 7]. The surface wetting transition is found to be pinned to the bulk monotectic point M in this alloy, and the topology of the bulk phase diagram enforces a path probing com plete wetting [8]. Since this path ends in M where four phase coexist, the surface transition constitutes a rare tetra point wetting e ect. An estimation of the capillary parameter ! indicates that uctuations a ect the observed complete SRW transition only marginally. A critical wetting transition with a similar value of ! should show more pronounced deviations from MF behavior. Here, how ever, this critical transition occurs on the m etastable extension of the 1/1 coexistence line som ewhere below T_M , and may be reachable only if the alloy supercools su ciently. Due to the mild e ect of the

uctuations, the surface potential driving the transition could be determ ined quantitatively. This is of particular im portance since in contrast with van-der-W aals interacting liquids, where the surface potential can be estim ated from the D zyaloshinski-Lifshitz-P itaevskii theory [4, 21], no equivalent theory is available for liquids with shortrange interaction. We hope that this rst quantitative determ ination of the SRW potential will stimulate the development of such theories. A vailable predictions, in turn, would initiate m ore experimental studies of uctuation e ects in SRW. In particular, they may allow a quantitative investigation of Parry's prediction of an additional renormalization of ! in SRW due to a coupling between the uctuations at the liquid/vapor and at the l/l interfaces[20]. This coupling may resolve the dichotom y between RG prediction and the observations in the single previous experimental study of SRW [6].

W e thank P rof. S.D ietrich and P rof. B J.Halperin for helpfuldiscussions. This work is supported by U S.DOE G rant No. DE-FG 02-88-ER 45379, NSF G rant NSF-DMR-98-72817, and the U S.-Israel B inational Science Foundation, Jerusalem. BNL is supported by U S.DOE C ontract No. DE-AC 02-98C H 10886. PH acknow ledges support from the D eutsche Forschungsgem einschaft.

- [1] J.W .Cahn, J.Chem .Phys. 66, 3667 (1977)
- [2] C.Ebner, W.F.Saam, Phys.Rev.Lett. 38, 1486 (1977)
- [3] P.G. de Gennes, Rev. M od. Phys. 57,827 (1985); S.D ietrich, in C.D om b, J.L. Lebow itz (Eds.), Phase Trans. and Crit. Phen., Vol. 12, A cad. Press, NY, 1988
- [4] B M. Law, Prog. Surf. Sci. 66, 159 (2001); D. Bonn and D. Ross, Rep. Prog. Phys. 64, 1085 (2001)
- [5] H.Gau et al., Science 283, 46 (1999); K.Kargupta et al. , Phys. Rev. Lett. 86, 4536 (2001);
- [6] D. Ross et al., Nature 400, 737 (1999); D. Ross et al., Phys. Rev. Lett. 87, 176103 (2001)
- [7] H.T. Davis, Statistical M echanics of Phases, Interfaces and Thin Film s, W iley-VCH, NY (1996)
- [8] S.D ietrich and M. Schick, Surf. Sci. 382, 178 (1997)
- [9] C. Serre et al, Surf. Sci. 415, 336 (1998)
- [10] P.Predel, Z.Phys.Chem.Neu.Fol.24, 206 (1960)
- [11] H. Tostm ann et al, Phys. Rev. Lett. 84, 4385 (2000)
- [12] N.Leiet al, J.Chem.Phys. 104, 4802 (1996)
- [13] P. Huber et al., in preparation.
- [14] P.S. Pershan, J. Als-Nielsen, Phys. Rev. Lett. 52, 759 (1984)
- [15] P.S.Pershan, Phys. Rev. E 50, 2369 (1994)
- [16] D. Nattland et al., J. Phys. C 7, L457 (1995)
- [17] K.B.Khokonov et.al, Sov.Electrochem . 10, 865 (1974)
- [18] E.Brezin et al.Phys.Rev.Lett.50, 1387 (1983); D.M. Krollet.al, Phys.Rev.B 32, 1862 (1985)
- [19] H.K reuser and D.W oerm ann, J.Chem. Phys. 98, 7655 (1993)
- [20] A.O. Parry, J. Phys. C, 8, 10761 (1996)
- [21] IE.D zyaloshinskiet.al, Adv. Phys. 10, 165 (1961)
- [22] The 1/1~ is calculated from the measured pro le using the Cahn-H illary theory [13].
- [23] The phase boundaries were calculated using data from the CalPhaD initiative (L.Kaufmann,MIT).